



Attorney Docket No.: SEL 139 DIV

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)
Shunpei Yamazaki et al.)
Serial No.: 09/808,162)
Filed: March 13, 2001)
For: Method For Fabricating A)
Semiconductor Device)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231 on May 4, 2001.

Signature Donna Janus-Moss
Date 5/4/2001

Commissioner for Patents
Washington D.C. 20231

29T80860

PRELIMINARY AMENDMENT

Dear Sir:

In the specification, on page 1, delete the cross reference to the related application and insert the following:

CROSS REFERENCE TO RELATED APPLICATION

This application is a continuation of copending U.S. Application Serial No. 09/386,782 filed on August 31, 1999.

In the Claims:

Please amend claims 1-3.

1. (Amended) A method of fabricating a semiconductor device, said method comprising the steps of:

GR preparing a single crystal semiconductor substrate having a main surface of a {110} surface;